

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Leonard J. Olmer, et al.

Serial No.: 10/675,575

Filed: September 30, 2003

Title: IN-SITU REMOVAL OF SURFACE IMPURITIES PRIOR TO ARSENIC-DOPED POLYSILICON DEPOSITION IN THE FABRICATION OF A HETEROJUNCTION BIPOLAR TRANSISTOR

Grp./A.U.: 1746

Examiner: Jason Mark Heckert

Confirmation No. 9967

For:

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

I hereby certify that this correspondence is being electronically filed
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October 29, 2007

Elizabeth Schumacher
(Printed or typed name of person signing the certificate)

/Elizabeth Schumacher/
(Signature of the person signing the certificate)

Sir:

PRELIMINARY AMENDMENT UNDER 37 C.F.R. § 1.114

In response to the Examiner's Action mailed September 18, 2007, please amend the above-identified application as follows: